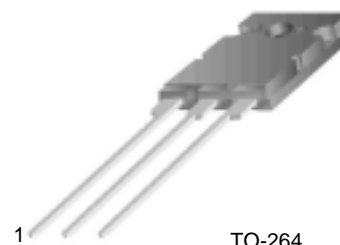


## FJL6820

### High Voltage Color Display Horizontal Deflection Output

- High Collector-Base Breakdown Voltage :  $V_{CB0} = 1500V$
- Low Saturation Voltage :  $V_{CE(sat)} = 3V$  (Max.)
- For Color Monitor



TO-264  
1.Base 2.Collector 3.Emitter

### NPN Triple Diffused Planar Silicon Transistor

#### Absolute Maximum Ratings $T_C=25^\circ C$ unless otherwise noted

Symbol	Parameter	Rating	Units
$V_{CB0}$	Collector-Base Voltage	1500	V
$V_{CEO}$	Collector-Emitter Voltage	750	V
$V_{EBO}$	Emitter-Base Voltage	6	V
$I_C$	Collector Current (DC)	20	A
$I_{CP}^*$	Collector Current (Pulse)	30	A
$P_C$	Collector Dissipation	200	W
$T_J$	Junction Temperature	150	$^\circ C$
$T_{STG}$	Storage Temperature	-55 ~ 150	$^\circ C$

\* Pulse Test:  $PW=300\mu s$ , duty Cycle=2% Pulsed

#### Electrical Characteristics $T_C=25^\circ C$ unless otherwise noted

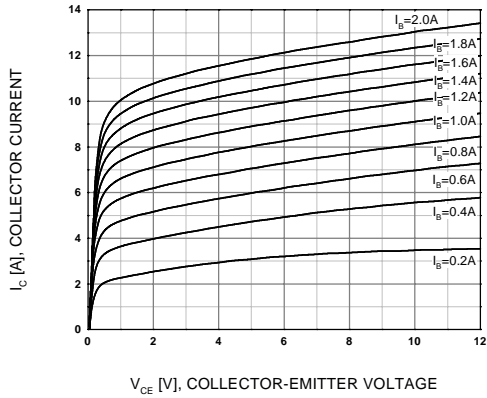
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
$I_{CES}$	Collector Cut-off Current	$V_{CB}=1400V, R_{BE}=0$			1	mA
$I_{CBO}$	Collector Cut-off Current	$V_{CB}=800V, I_E=0$			10	$\mu A$
$I_{EBO}$	Emitter Cut-off Current	$V_{EB}=4V, I_C=0$			1	mA
$V_{CB0}$	Collector-Base Breakdown Voltage	$I_C=500\mu A, I_E=0$	1500			V
$V_{CEO}$	Collector-Emitter Breakdown Voltage	$I_C=5mA, I_B=0$	750			V
$V_{EBO}$	Emitter-Base Breakdown Voltage	$I_E=500\mu A, I_C=0$	6			V
$h_{FE1}$	DC Current Gain	$V_{CE}=5V, I_C=1A$	8			
$h_{FE2}$		$V_{CE}=5V, I_C=8.5A$	6		10	
$h_{FE3}$		$V_{CE}=5V, I_C=11A$	5.5		8.5	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C=11A, I_B=2.75A$			3	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C=11A, I_B=2.75A$			1.5	V
$t_{STG}^*$	Storage Time	$V_{CC}=200V, I_C=10A, R_L=20\Omega$			3	$\mu s$
$t_F^*$	Fall Time	$I_{B1}=2.0A, I_{B2}=-4.0A$		0.15	0.2	$\mu s$

\* Pulse Test:  $PW=20\mu s$ , duty Cycle=1% Pulsed

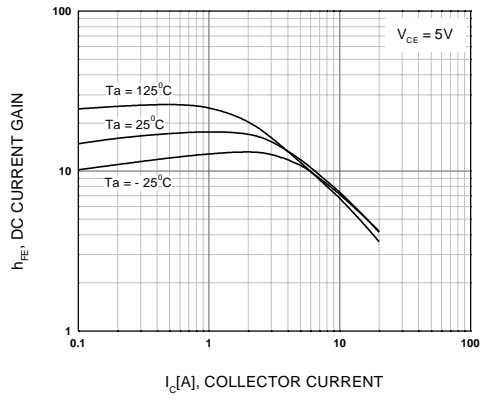
#### Thermal Characteristics $T_C=25^\circ C$ unless otherwise noted

Symbol	Parameter	Typ	Max	Units
$R_{\theta JC}$	Thermal Resistance, Junction to Case		0.625	$^\circ C/W$

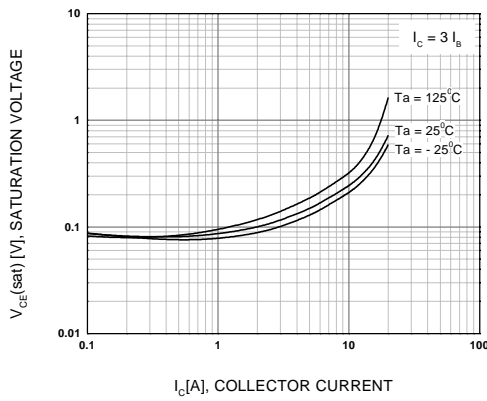
# Typical Characteristics



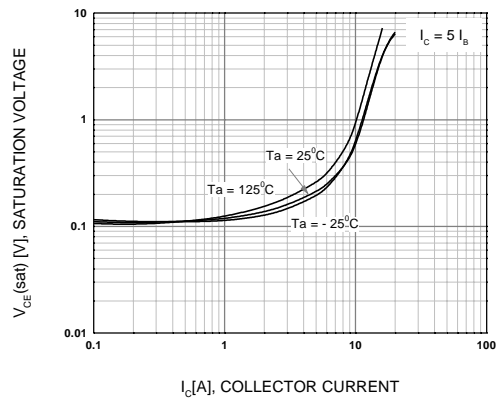
**Figure 1. Static Characteristics**



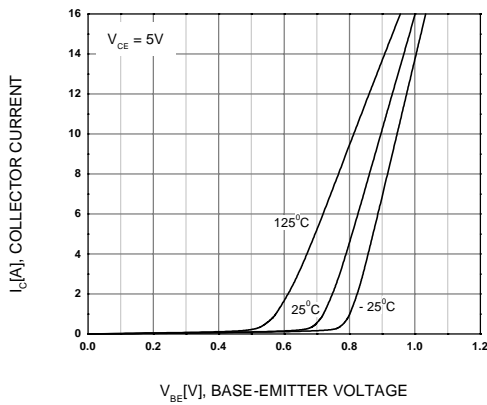
**Figure 2. DC Current Gain**



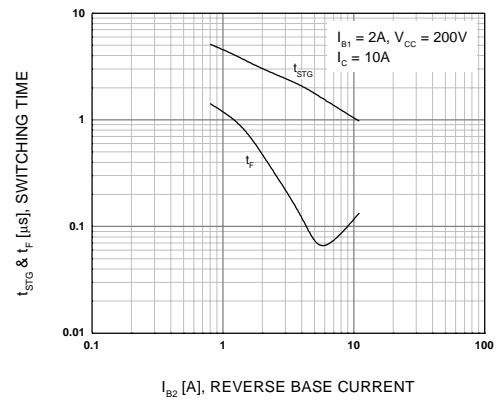
**Figure 3. Collector-Emitter Saturation Voltage**



**Figure 4. Collector-Emitter Saturation Voltage**



**Figure 5. Base-Emitter On Voltage**



**Figure 6. Resistive Load Switching Time**

## Typical Characteristics (Continued)

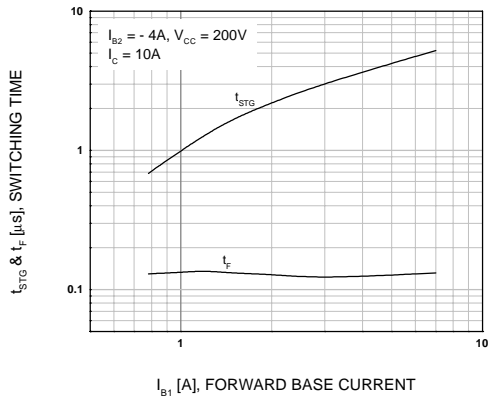


Figure 7. Resistive Load Switching Time

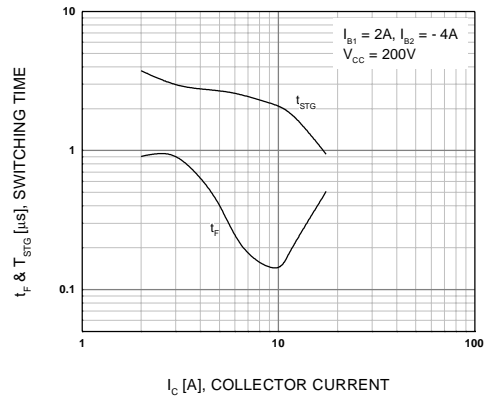


Figure 8. Resistive Load Switching Time

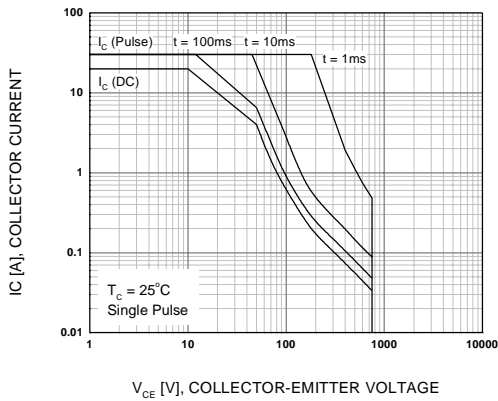


Figure 9. Forward Bias Safe Operating Area

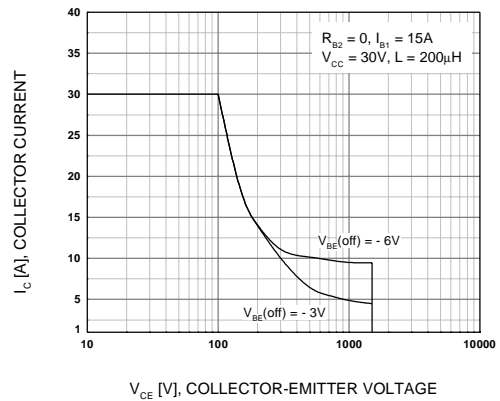


Figure 10. Reverse Bias Safe Operating Area

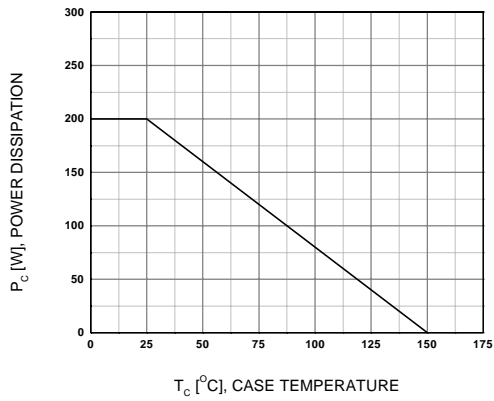
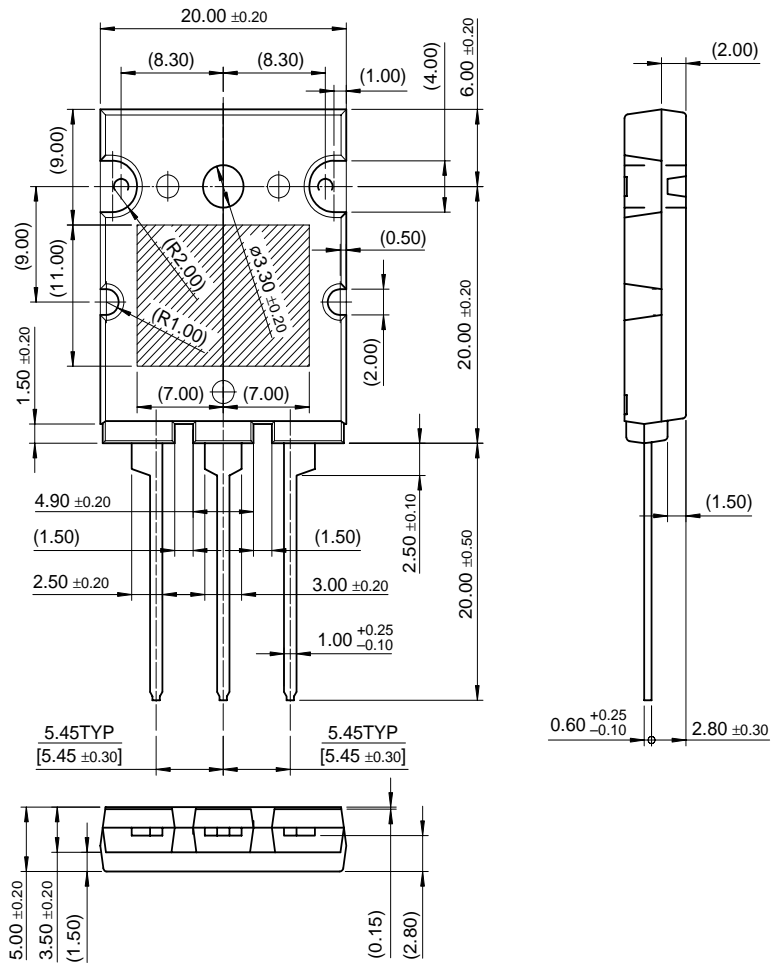


Figure 11. Power Derating

# Package Dimensions

## TO-264



Dimensions in Millimeters

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Bottomless™	FAST <sup>r</sup> ™	PACMAN™	SuperSOT™-6
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DenseTrench™	GTO™	QFET™	TinyLogic™
DOME™	HiSeC™	QS™	UHC™
EcoSPARK™	ISOPLANAR™	QT Optoelectronics™	UltraFET <sup>®</sup>
E <sup>2</sup> CMOS™	LittleFET™	Quiet Series™	VCX™
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